

Current Limited Load Switch

DESCRIPTION

The EUP3510 is a Current Limited P-channel MOSFET power switch designed for high-side load-switching applications. An integrated current-limiting circuit protects the input supply against large currents which may cause the supply to fall out of regulation. It can be used to control loads that require up to 1A. In order to fit different application, current limit threshold is programmed with a resistor from SET Pin to ground. The quiescent supply current is typically a low $8\mu A$, making the device ideal for portable battery-operated equipment. In shutdown mode, the supply current decreases to less than $0.1\mu A$.

Additional features include thermal shutdown to prevent catastrophic switch failure from high current loads, under-voltage lockout (UVLO) to ensure that the device remains off unless there is a valid input voltage present.

The EUP3510 is available in a 5 pin SOT-23 package.

FEATURES

- 2.4V to 5.5V Input voltage range
- Programmable over current threshold
- Fast transient response:
- Low quiescent current
 - 8μA typical
 - 1µA max with shutdown
- 135m Ω typical R_{DS(ON)}
- Only 1.8V needed for ON/OFF Control
- Under-Voltage Lockout
- Thermal shutdown
- Temp range -40 to 85°C
- Available in SOT23-5 package
- RoHS Compliant and 100% Lead(Pb)-Free

APPLICATIONS

- Peripheral ports
- Notebook computers
- Personal communication devices
- Hot swap supplies

Typical Application Circuit

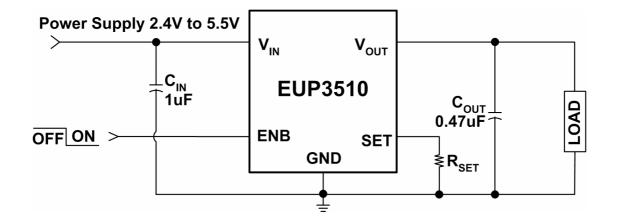


Figure 1.



Block Diagram

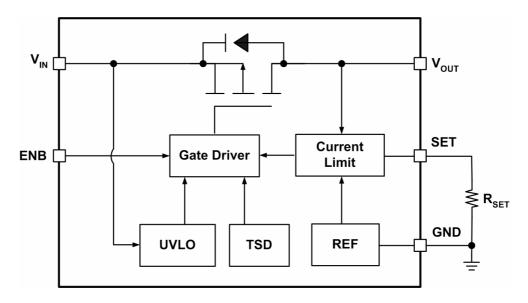


Figure 2.

Pin Configurations

Package Type	Pin Configurations		
SOT23-5	V _{IN} ENB 5 4 1 2 3 V _{OUT} GND SET		

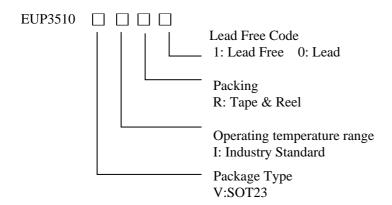
Pin Description

PIN	NAME	DESCRIPTION
1	V _{OUT}	P-type MOSFET Drain, connect 0.47uF capacitor from V _{OUT} to Ground
2	GND	Ground
3	SET	Current-Limit Set Input. A resistor R_{SET} from SET to ground sets the current limit for the switch
4	ENB	Enable Input, active-low
5	V _{IN}	P-channel MOSFET Source, connect 1uF capacitor from V _{IN} to Ground



Ordering Information

Order Number	Package Type	Marking	Operating Temperature Range
EUP3510VIR1	SOT23-5	40xxxx	-40 °C to 85°C





Absolute Maximum Ratings

-	Supply Voltage (V _{IN} to GND)	0.3	V to 6V
•	Supply Voltage (ENB to GND)	-0.3V to	$V_{IN}+0.3$
•	Output Voltages (SET,V _{OUT} to GND)	-0.3V to	$V_{IN}+0.3$
•	Storage Temperature	-65°C t	o 150°C
•	Reflow Temperature (soldering, 10sec)		260°C
•	Thermal Resistance θ_{JA} (SOT23-5)	:	220°C/W
•	ESD Rating		
	Human Body Model		2kV

Operating Ratings

- Supply Voltage (V_{IN}) ------- 2.4V to 5.5V

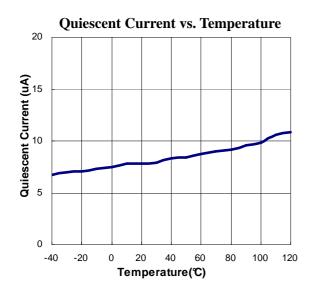
Electrical Characteristics

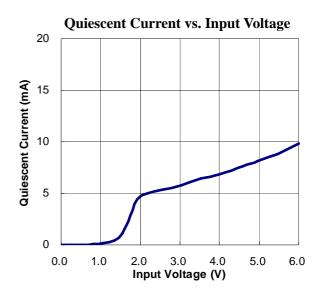
Unless otherwise specified, V_{IN} = 5V, C_{IN} =1uF, C_{OUT} =0.47uF, T_A =-40°C ~+85°C.

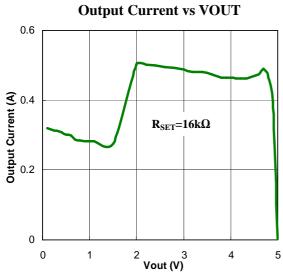
Symbol	Parameter	Conditions	EUP3510			Units
Symbol	1 ai ainetei	Conditions	Min. Typ. Max.			
$V_{\rm IN}$	Operating Voltage		2.40		5.50	V
		V _{IN} =5V		135	205	mΩ
$R_{DS(ON)}$	On-Resistance	$V_{IN}=4.5V$		140	210	mΩ
		$V_{IN}=3V$		160	240	mΩ
I_{LIM}	Current Limit	V_{OUT} =0V,Rset=6.8K Ω	750	1035	1225	mA
I_Q	Quiescent Current	$V_{IN}=5V$, $V_{ON}=0V$, $I_{OUT}=0A$		8.1	11.5	uA
I _{Q(OFF)}	Off Supply Current VIN Under Voltage Lockout	V _{IN} =5V, V _{ON} =5V, I _{OUT} =0A		0.1	1	uA
$V_{\rm UVLO}$		V _{IN} Falling	1.22	1.55	1.91	V
$V_{\text{UVLO-HYS}}$	VIN Under Voltage Hysteresis	V _{IN} Rising		185		mV
V _{ON(L)}	ON Input Low Voltage	V _5V	1.16	1.30	1.36	V
V _{ON(H)}	ON Input Hige Voltage	$ V_{IN}=5V$	1.26	1.51	1.55	V
I _{ON(SINK)}	ON Input leakage	V _{ON} =5V		0.1	1	uA
TOFF	Turn_Off Time	$V_{IN}=5V$, $R_L=10\Omega$		12		us
TON	Turn_On Time	$V_{IN}=5V$, $R_L=10\Omega$		20		us
T_{SD}	Thermal Shutdown Temp.			135		°C
T _{SD-HYS}	T _{SD} Hysterisis			20		°C

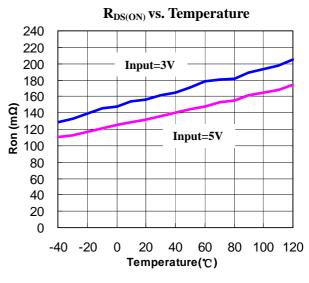


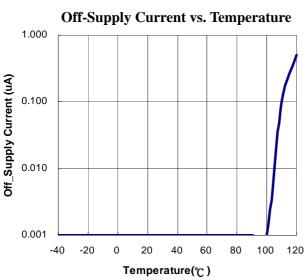
Typical Operating Characteristics (unless otherwise noted ,V_{IN}=5V, T_A=25°C.)

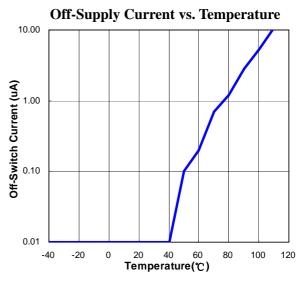




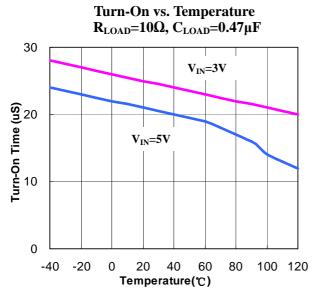


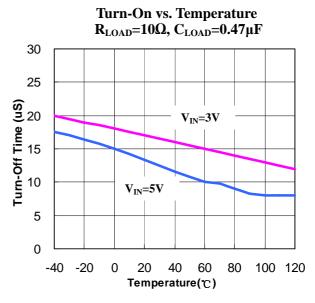


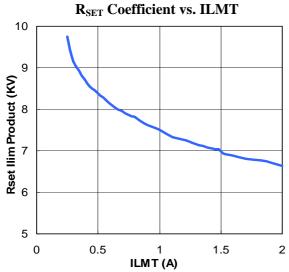


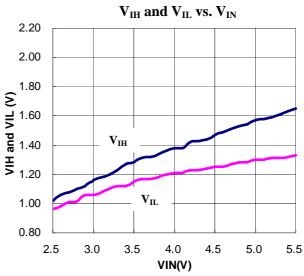


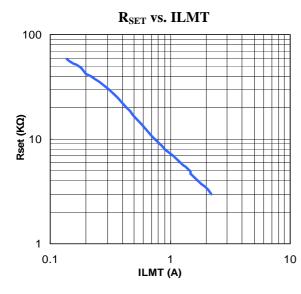
Typical Operating Characteristics (unless otherwise noted ,V_{IN}=5V, T_A=25°C.)



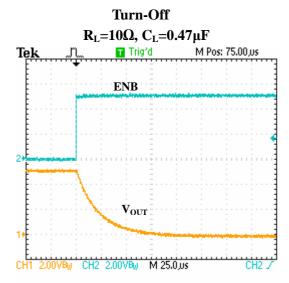


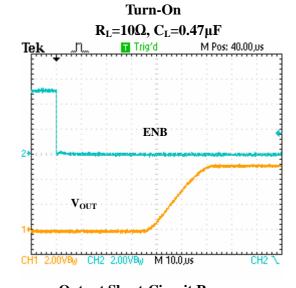


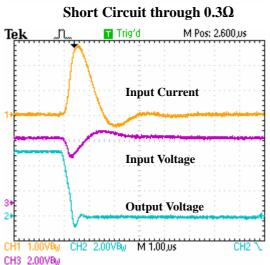


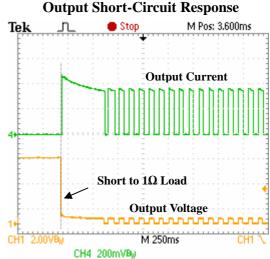


Typical Operating Characteristics (unless otherwise noted ,V_{IN}=5V, T_A=25°C.)









Detailed Description

The EUP3510 limits load current by sampling the pass transistor current and passing that through an external resistor, R_{SET} . The voltage across R_{SET} , V_{SET} , is then compared with an internal reference voltage, V_{REF} . In the event that load current surpasses the set limit current, V_{SET} will exceed V_{REF} causing the pass transistor gate voltage to increase, thereby reducing the gate to source voltage of the PMOS switch and regulating its current back down to I_{LIMIT} .

When the device detect V_{OUT} is less than 1V, the limit current will fold-back to about 60% of I_{LMT} .

Setting the Current Limit Level

Setting the current limit level on the EUP3510 requires some care to ensure the maximum current required by the load will not trigger the current limit circuitry. The minimum current limit threshold should be determined by taking the maximum current required by the load, $I_{\rm LOAD}$, and adding 25 % headroom. The EUP3510 has a current limit tolerance of 25 %, which is largely a result of process variations from part to part, and also temperature and $V_{\rm IN}/V_{\rm OUT}$ variances. Thus, to ensure that the actual current limit is never below the desired current limit a 1/0.75 = 1.33 coefficient needs to be added to the calculations. Knowing the maximum load current required, the value of $R_{\rm SET}$ is calculated as follows.

$$R_{SET} = R_{SET} cofficient / I_{LIMIT}$$

where $I_{LIMIT} = (I_{LOAD} \times 1.33) \times 1.25$ and R_{SET} coefficient is 7500 for a 1A current limit. For typical R_{SET} coefficient values given a limit current refer to the "Typical Characteristics" section.

Operating at Current Limit and Thermal Shutdown

In the event that a load higher than I_{LIMIT} is demanded of the EUP3510, the load current will stay fixed at the current limit established by R_{SET} . However, since the required current is not supplied, the voltage at OUT will drop. The increase in V_{IN} - V_{OUT} will cause the chip to dissipate more heat. The power dissipation for the EUP3510 can be expressed as

$$P = I_{LOAD} \times (V_{IN} - V_{OUT})$$

Once this exceeds the maximum power dissipation of the package, the die temperature will rise. When the die temperature exceeds an over-temperature limit of 135 °C, the EUP3510 will shut down until it has cooled down to 115°C, before starting up again. As can be seen in the figure below, the EUP3510 will continue to cycle on and off until the load is reduced or the part is turned off.

The maximum power dissipation in any application is dependant on the maximum junction temperature, $T_{J(MAX)}$ =125°C, the junction-to-ambient thermal resistance for the SOT23-5 package, θ_{JA} =220 °C/W, and the ambient temperature, T_A , which may be formulaically expressed as:

$$P(max) = \frac{T_{J(max)} - T_A}{\theta_{JA}} = \frac{125 - T_A}{220}$$

It then follows that assuming an ambient temperature of 60°C, the maximum power dissipation will be limited to about 295 mW.

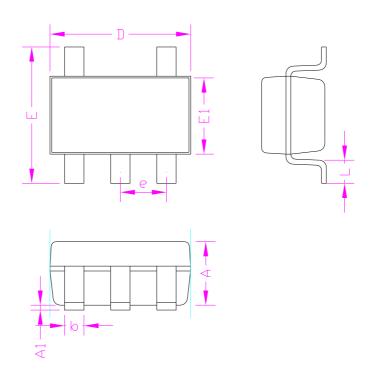
Reverse Voltage

The EUP3510 is designed to control current flowing from IN to OUT. If the voltage on OUT is raised higher than IN current will flow from OUT to IN but the current limit function will not be available, as can be inferred from the block diagram in Figure 2. Thus, in applications were OUT is used to charge IN, careful considerations must be taken to limit current through the device and protect it from becoming damaged.



Packaging Information

SOT23-5



SYMBOLS	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	-	1.30	-	0.052	
A1	0.00	0.15	0.000	0.006	
D	2.90		0.114		
E1	1.60		0.063		
Е	2.60	3.00	0.102	0.118	
L	0.30	0.60	0.012	0.024	
b	0.30	0.50	0.012	0.020	
e	0.95 0.037		37		

